

Classical and new approaches to thin film photovoltaics

Claudio Manfredotti

World PV module production

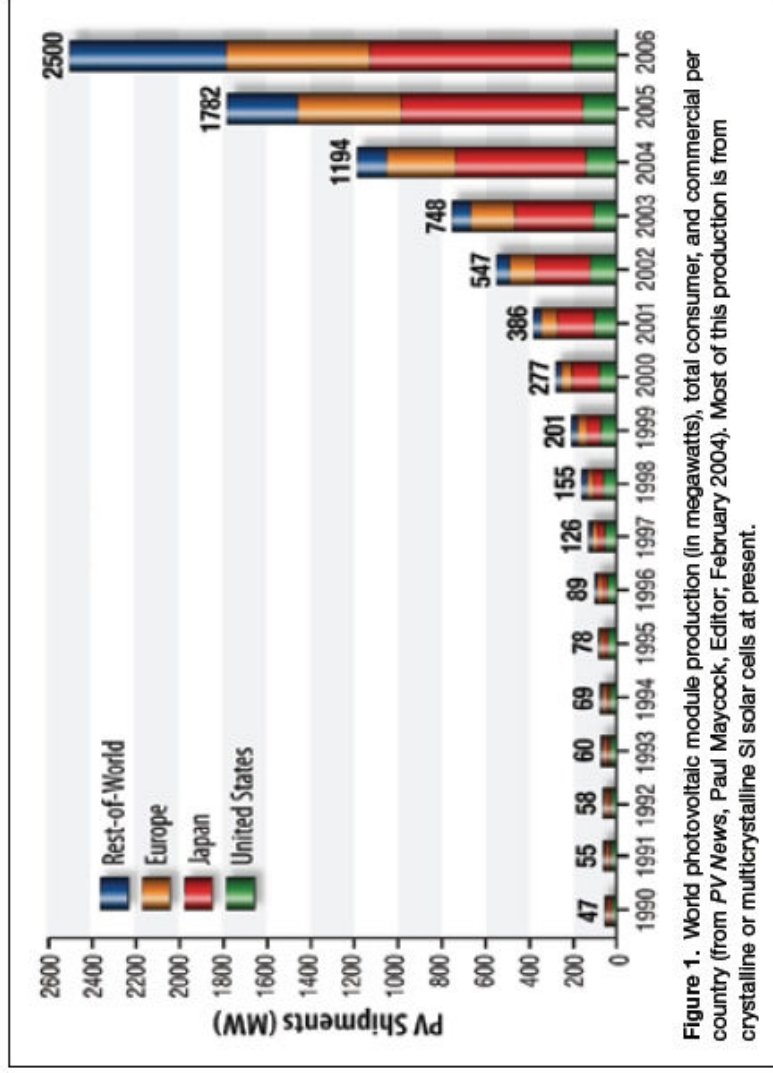


Figure 1. World photovoltaic module production (in megawatts), total consumer, and commercial per country (from PV News, Paul Maycock, Editor, February 2004). Most of this production is from crystalline or multicrystalline Si solar cells at present.

PV companies in the world

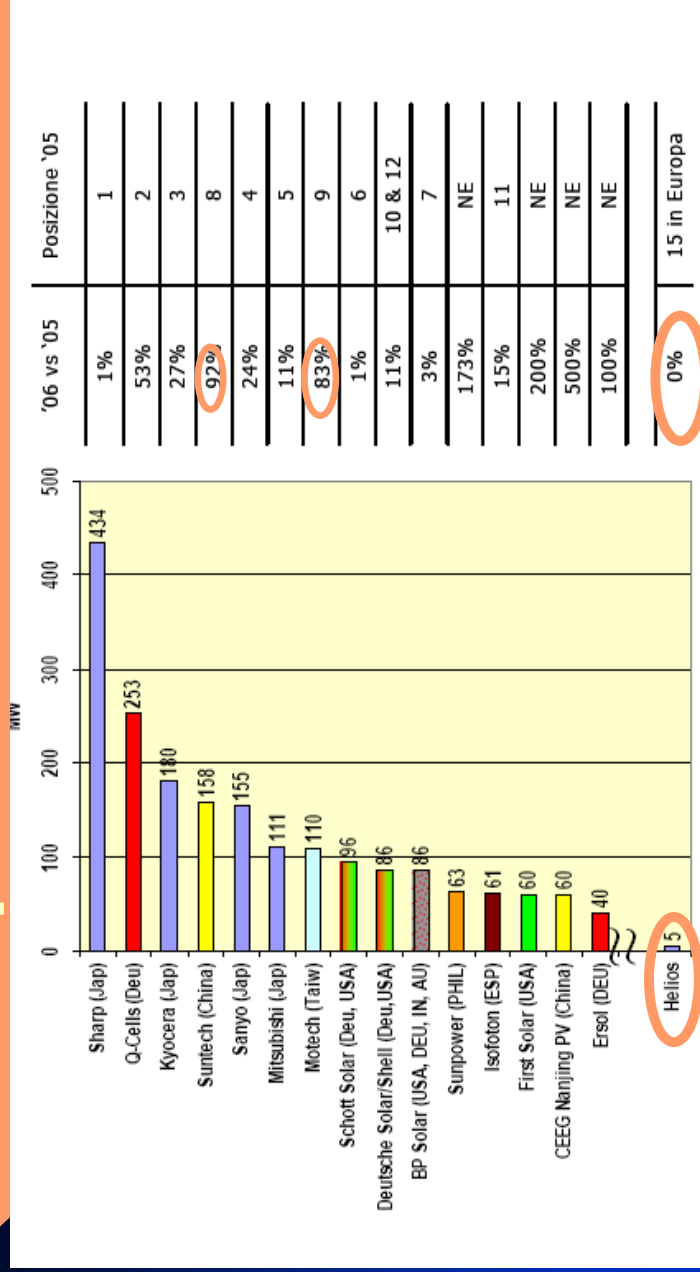


Figura 6 - I maggiori produttori del mercato fotovoltaico mondiale 2006, i loro incrementi di produzione rispetto all'anno precedente e la posizione che occupavano nel 2005 (Fonte: PV News, Aprile 2007)



Principali strutture pubbliche di ricerca nel settore fotovoltaico

Organizzazione	Area di Ricerca & Sviluppo
ENEA	Tecnologie del silicio cristallino, a film sottile e a eterogiunzione. Sistemi a concentrazione. Qualificazione componenti e sistemi. Integrazione architettonica. Normativa.
CESI Ricerca	Tecnologie delle multigiunzioni III-V per applicazioni spaziali e terrestri a concentrazione. Sistemi. Normativa.
CNR IMM Bologna	Tecnologie del silicio cristallino a eterogiunzione.
CNR Bari	Tecnologie del silicio a film sottile.
CNR IMEM Parma	Tecnologie dei materiali III-V.
CNR ISOF Bologna	Tecnologie delle celle solari organiche.
CNR ISMAC Milano	Tecnologie delle celle solari organiche.
CNR IMM Lecce	Tecnologie dei materiali III-V, del silicio a film sottile e del termofotovoltaico.
Università di Milano Bicocca	Tecnologie del silicio cristallino e a film sottile.
Politecnico di Milano	Integrazione architettonica.
Politecnico di Torino	Tecnologia dei convertitori statici di potenza.
Università di Ferrara	Tecnologie del silicio cristallino. Celle dye-sensitized. Sistemi a concentrazione.
Università di Bologna	Tecnologie delle celle solari organiche.
Università di Parma	Tecnologie del CdTe e del CIGS a film sottile. Tecnologie dei materiali III-V.
Università di Firenze	Tecnologie per la produzione del silicio.
Università di Camerino	Tecnologie dei materiali III-V.
Università di Roma 1	Tecnologie del silicio a film sottile e a eterogiunzione.
Università di Roma 2	Tecnologie delle celle dye-sensitized.
Università di Napoli 1	Tecnologie del silicio cristallino. Modellistica.
Università di Salerno	Modellistica e caratterizzazioni. Tecnologia dei convertitori statici di potenza.
Università di Palermo	Tecnologia dei convertitori statici di potenza.
CCR IES Ispra	Certificazione di moduli fotovoltaici. Normativa.

Public research centres in Italy

Fonte : ENEA

PV installations in Europe

Tabella 4 - Potenza complessiva delle nuove installazioni di impianti fotovoltaici nei Paesi europei più impegnati, relativa agli anni 2005 e 2006 (Fonte EurObserv'ER, 2007)

Paesi	2005	2006
	nuove installazioni in MW	
Germania	866	1153
Spagna	14,5	60,5
Italia	15,6	11,6
Francia	5,3	6,4
Austria	4,8	5
Gran Bretagna	2,7	2,7
Belgio	0,8	2,1
Grecia	0,9	1,2
Svezia	0,4	0,6
Cipro	n.d.	0,5
Portogallo	0,3	0,5
Olanda	1,7	0,4
Totale	913	1244,5

1 % !

Fonte : ENEA

PV industrial production in Italy

Tabella 7 - Capacità produttiva attuale e attesa delle principali compagnie impegnate nella produzione di celle e moduli fotovoltaici in Italia

Compagnia	Tecnologia	Capacità attuale (MW/anno)	Capacità attesa (2009) (MW/anno)
Enipower	celle cSi / moduli	10	10
Helios Technology	celle cSi / moduli	8	40
Istar solar	Moduli	4,5	10
Renegies	Moduli	1,1	30
SE Project	Moduli	10	50
Solarday	Moduli	10	25
Omnia Solar	celle cSi	1	30
XGroup	celle cSi / moduli	1	100
Soluxia	Moduli		12
Elettrosannio	Moduli	1	3
Blu minipower	Moduli		10
Solsonica	celle cSi / moduli		30
Arendi	Moduli CdTe		18
Totale		46,6	368

Fonte : ENEA

PV power in Italy

Tabella 5 – Potenza cumulata relativa alle diverse tipologie di impianti fotovoltaici installati in Italia

Tipologia	1987	1992	1997	2002	2007 (luglio)
off-grid industriali	2,3	3,7	4,8	6,4	7,7
off-grid domestici	3,0	4,0	5,0	5,3	5,6
on-grid centralizzati	0,2	0,7	6,2	6,7	7,7
on-grid distribuiti	0,0	0,1	0,7	3,6	49,2
Totale	5,5	8,5	16,7	22,0	70,2
Crescita media annuale		11%	20%	6%	44%

Fonte : ENEA

Progress in PV energy conversion efficiency

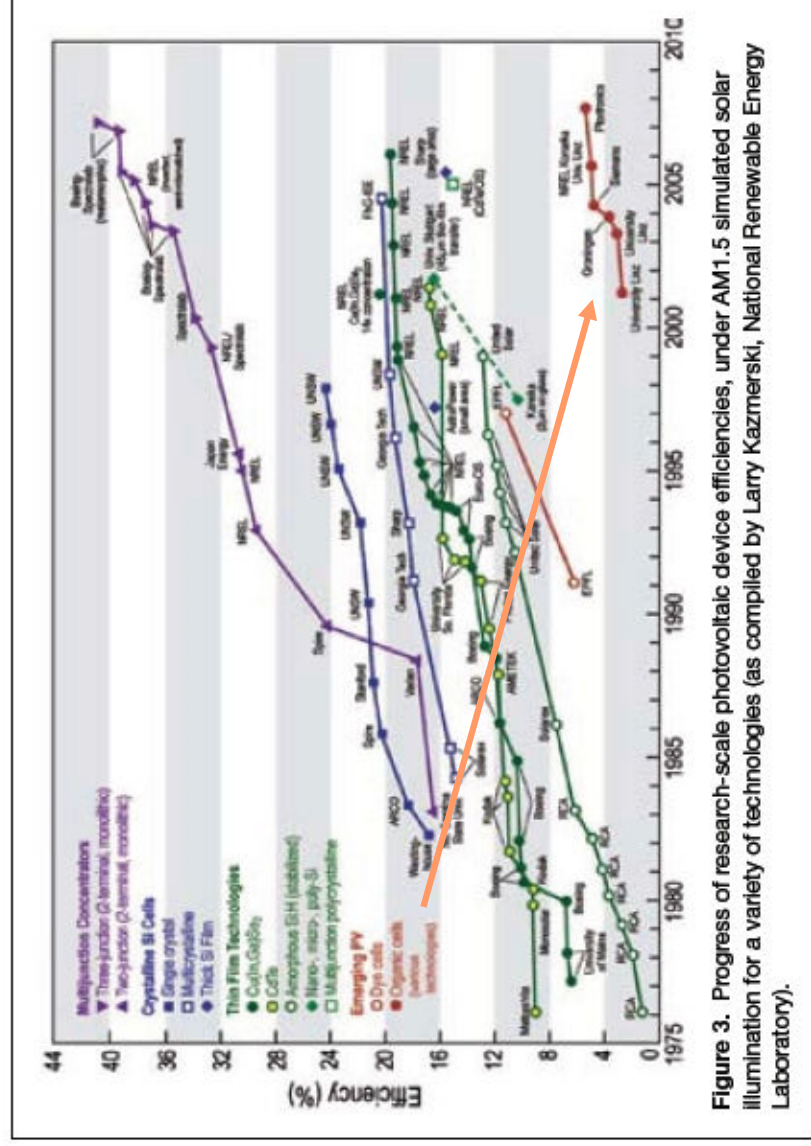


Figure 3. Progress of research-scale photovoltaic device efficiencies, under AM1.5 simulated solar illumination for a variety of technologies (as compiled by Larry Kazmerski, National Renewable Energy Laboratory).

NREL

• EFFICIENCY ?

• STABILITY ?

• COST ?

New technologies or just reducing the cost ?

June 16, 2008

SOLARCELL

Solar Cells Cost Could Fall Below One Dollar Per Watt By 2020

Dublin, Ireland (SPX) Jun 16, 2008
Conditions within the power industry have changed significantly in recent years. The rising cost of natural gas has made this an expensive source of power, while concern about global warming and the introduction of limits on CO2 emissions will have a profound effect on the use of coal for power generation, at least in the developed world. In consequence nuclear power has its best chance of ...
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one cell at a time

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- ◆ US envoy says no '08 solution to climate change
- ◆ Thousands evacuated as rains lash China quake region
- ◆ Radioactive traces found in Italy hospital waste: reports
- ◆ Food, environment to dominate G8 summit: Japan PM
- ◆ Losing just 15 buildings ribs heart out of flooded Iowa town
- ◆ Climate change threatening coral reef fish: Australian researchers
- ◆ Flash floods, mudslides kill 25 in India's northeast
- ◆ China starts to evacuate up to 70,000 from quake zone over rain: report
- ◆ China starts to evacuate up to 70,000 from quake zone: report



Jet & Rocket Engine Test Services



Mammoth Farm



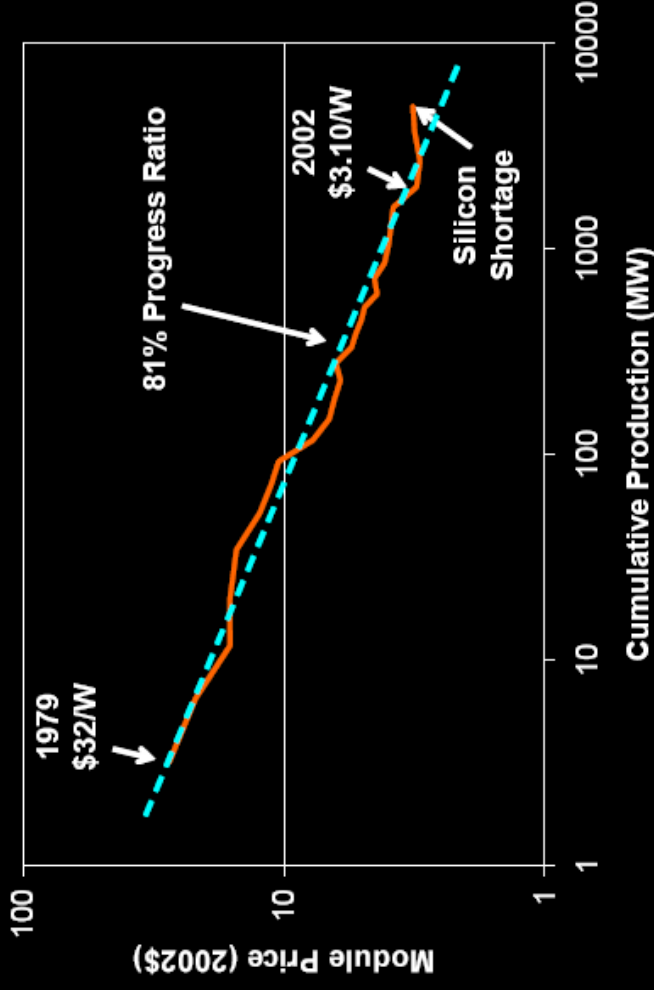
Shen for



Solar Energy

SUNPOWER Solar Price Learning Curve

Solar Panel Cost Drops by 19%
With Each Doubling in Manufacturing Capacity

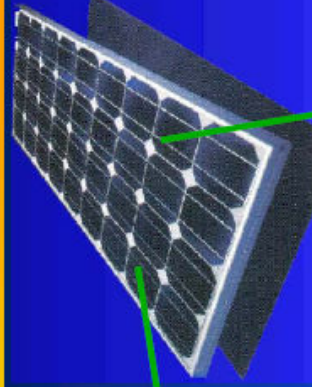
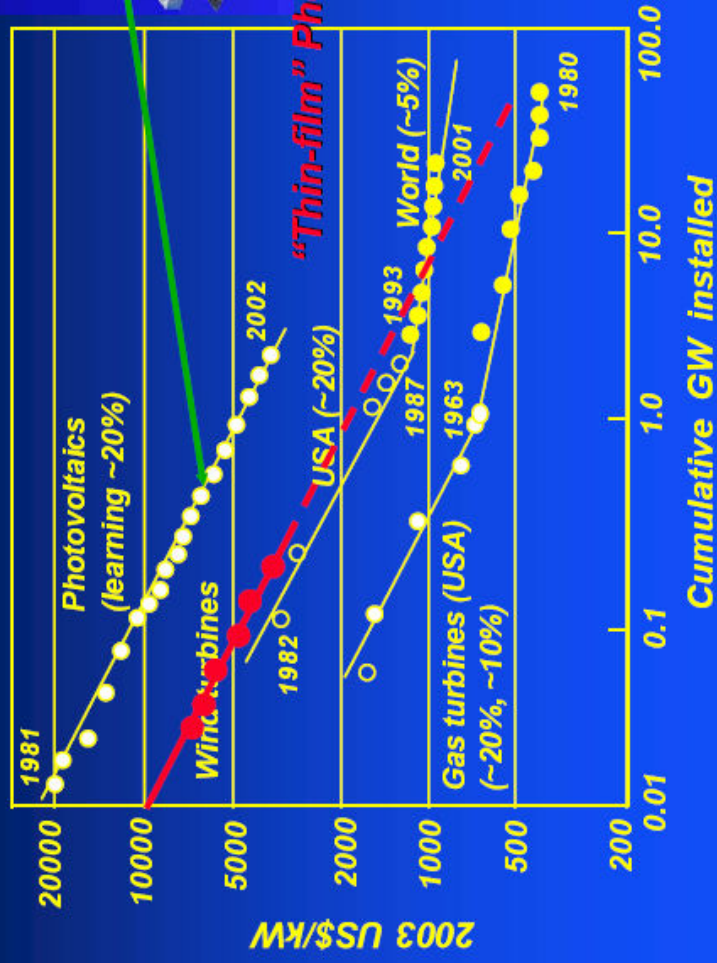


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Cost reduction



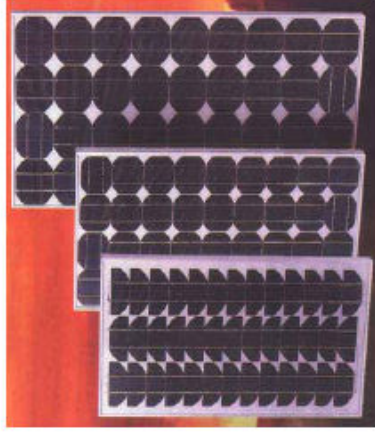
"Thin-film" Photovoltaics



Thin-film

Adapted from Grubler et al., 1999
Photovoltaics - Electricity from Sunlight

Solar cell technologies



1st Generation

Silicon wafer

- Thickness: **> 250 μm**
 - Area limited by wafer size
 - Rigid
 - Complex module integration
- ⇒ **Expensive**

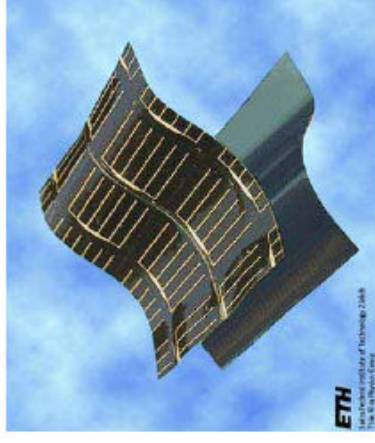
Si wafer



2nd Generation

Thin-film on glass

- Thickness: **< 3 μm**
 - Large area deposition
 - Rigid
 - Monolithic module integration
- ⇒ **Low cost potential**

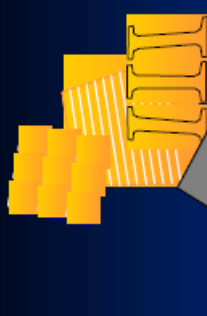


3rd Generation

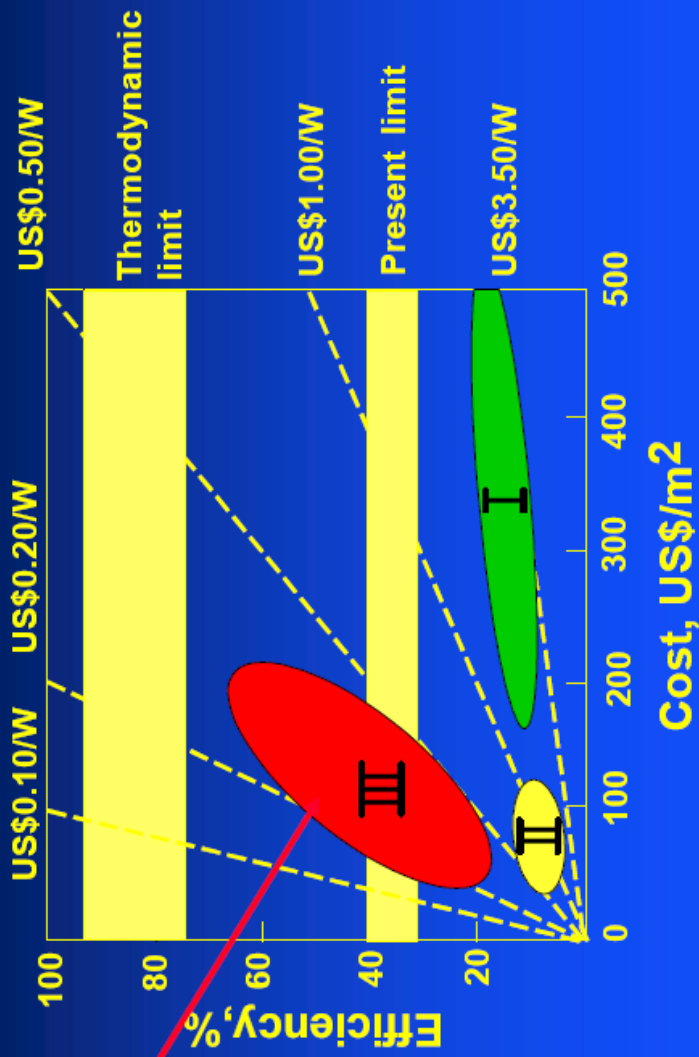
Thin film – on plastic

- Thickness: **< 3 μm**
 - Large area possible
 - Flexible
 - Easy module integration
- ⇒ **Low cost potential**

1. Amorphous Si; 2. CdTe; 3. CIGS



The 3 generations



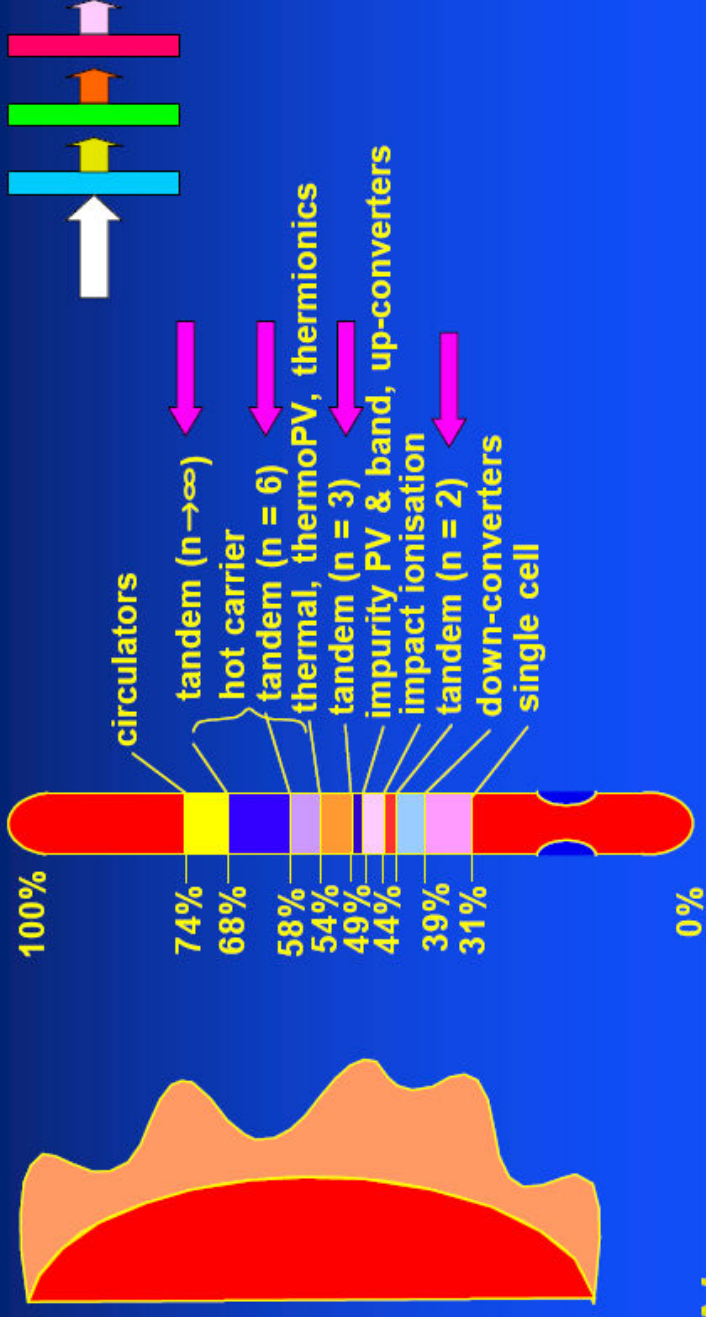
- *high-efficiency*
- *thin-film*
- *abundant*
- *non-toxic*
- *durable*

UNSW

Photovoltaics - Electricity from Sunlight



Third generation options



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Possible future scenarios

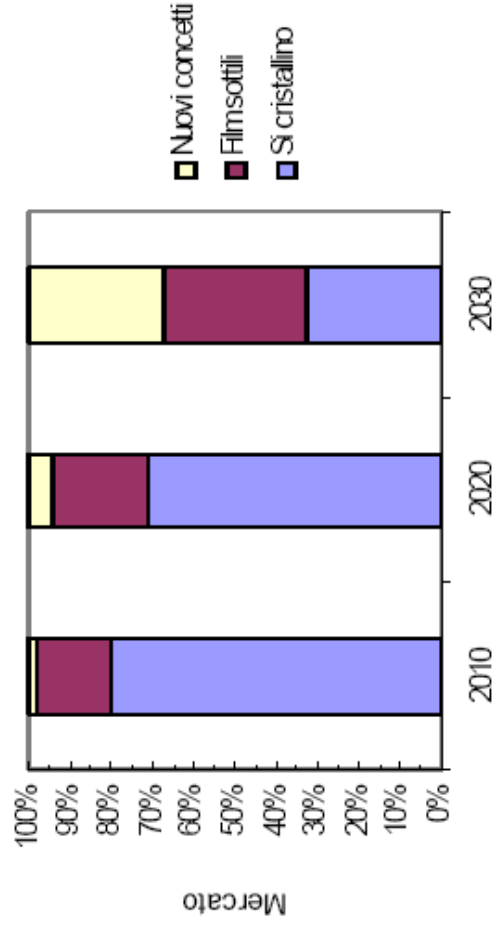
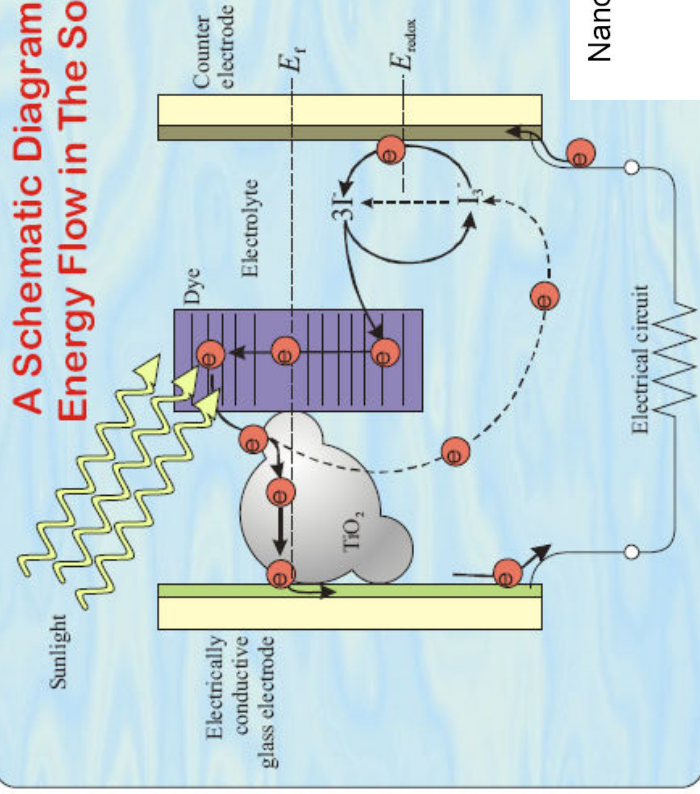


Figura 4 – Previsioni della ripartizione del mercato per tecnologie a breve, medio e lungo termine. Tra i nuovi concetti, oltre alle tecnologie emergenti è compreso il fotovoltaico a concentrazione (Fonte: EPIA, 2007)

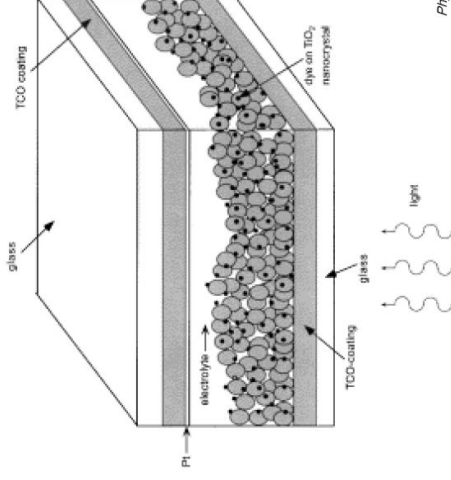
Fonte : ENEA

A Schematic Diagram of The Energy Flow in The Solar Cell



DSSC Dye Sensitized Solar Cells

Nanocrystalline TiO_2 dye-sensitised solar cell

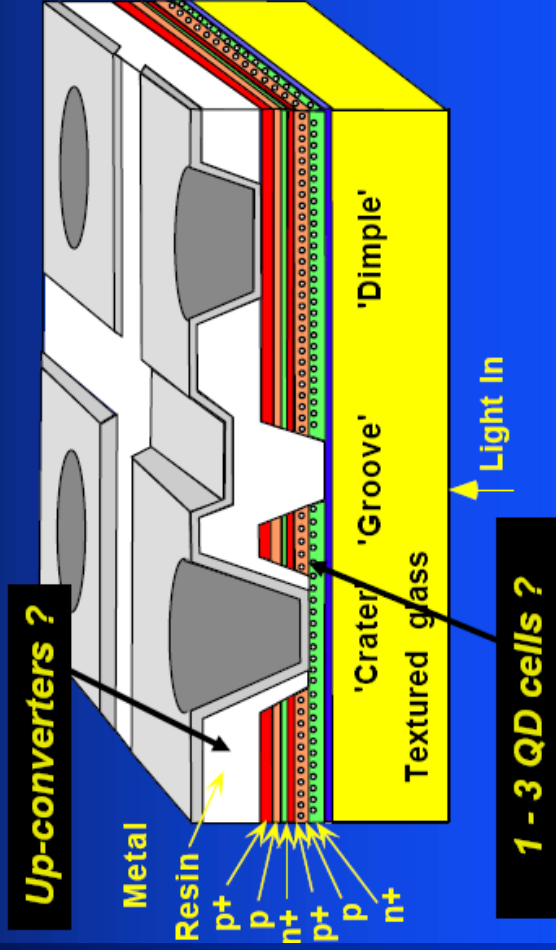




Si-tandem concept

CSG Solar approach

- . high-T silicon
- . high-density contacts
- . good optics
- . deposit then process
- . also suits hot-carrier



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High efficiency Si solar cells

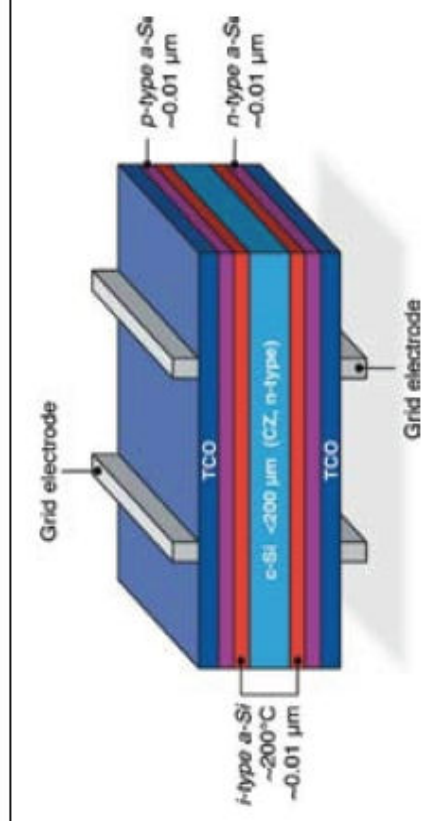
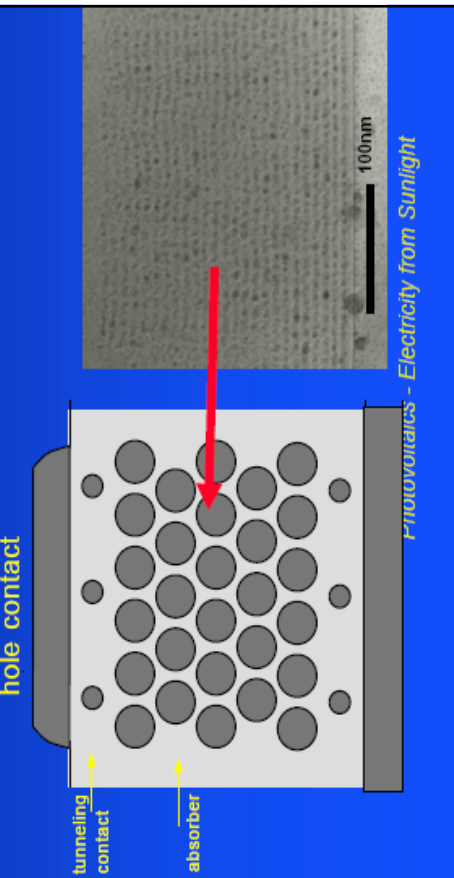
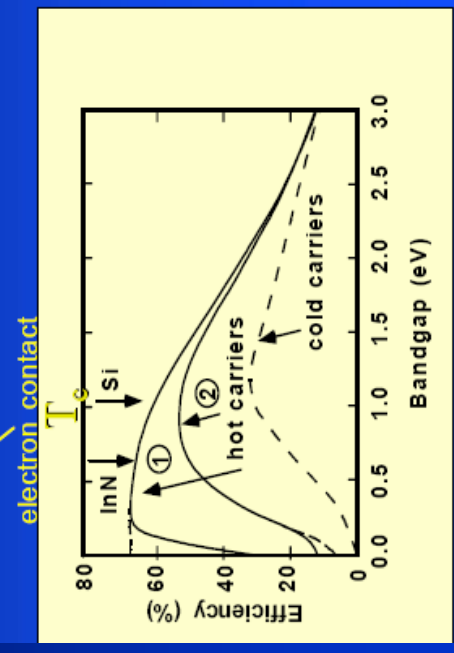
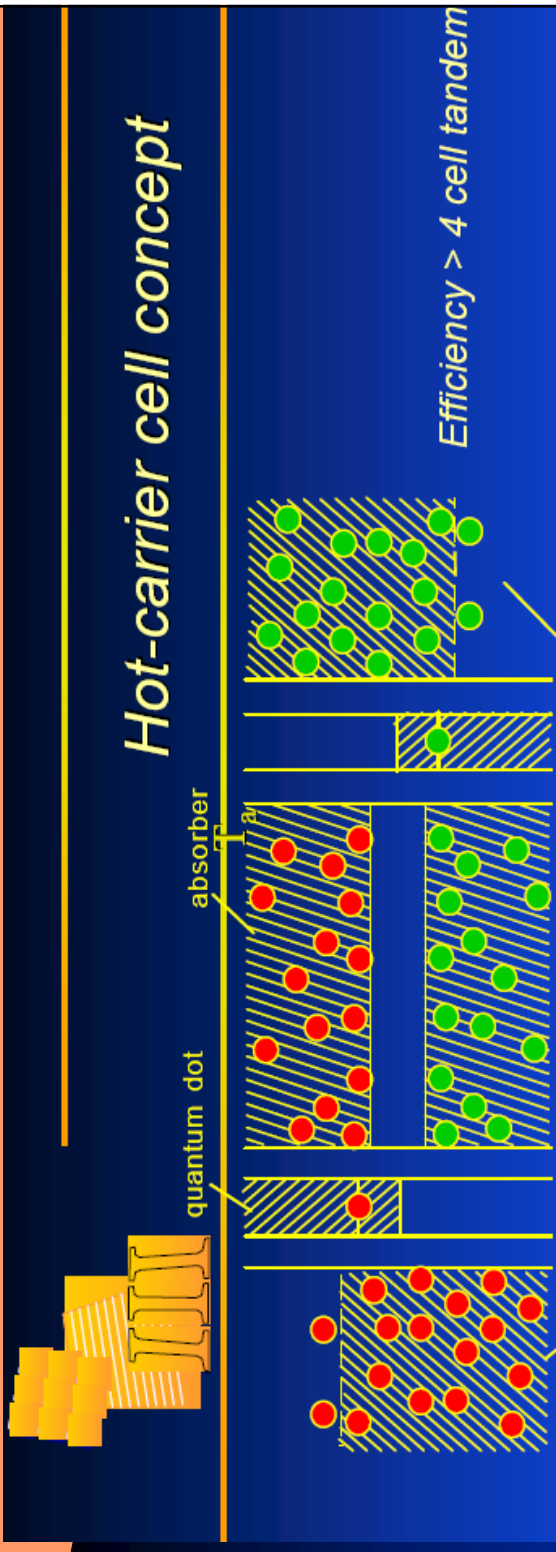


Figure 2. Illustration of the Sanyo heterojunction with intrinsic thin layer (HIT) cell that is based on crystalline Si and has demonstrated a 22% efficiency. TCO means transparent conducting oxide, typically used as a contact, and CZ indicates Czochralski-grown, which means pulled from the melt as a single crystal. The three types of amorphous silicon (a-Si) included in the cell differ in the types of dopants (or impurities) that have been added: *i*-type (or intrinsic) is undoped, *n*-type contains a dopant (such as phosphorus) that increases the number of free negative charge carriers (i.e., electrons), and *p*-type contains a dopant (such as boron) that increases the number of free positive charge carriers (i.e., holes). The types and amounts of impurities in the silicon affect its conductivity and other properties.

Hot-carrier cell concept



PHOTONICS - Electricity from Sunlight

Quantum Dots Solar Cells (Nozik, NREL)

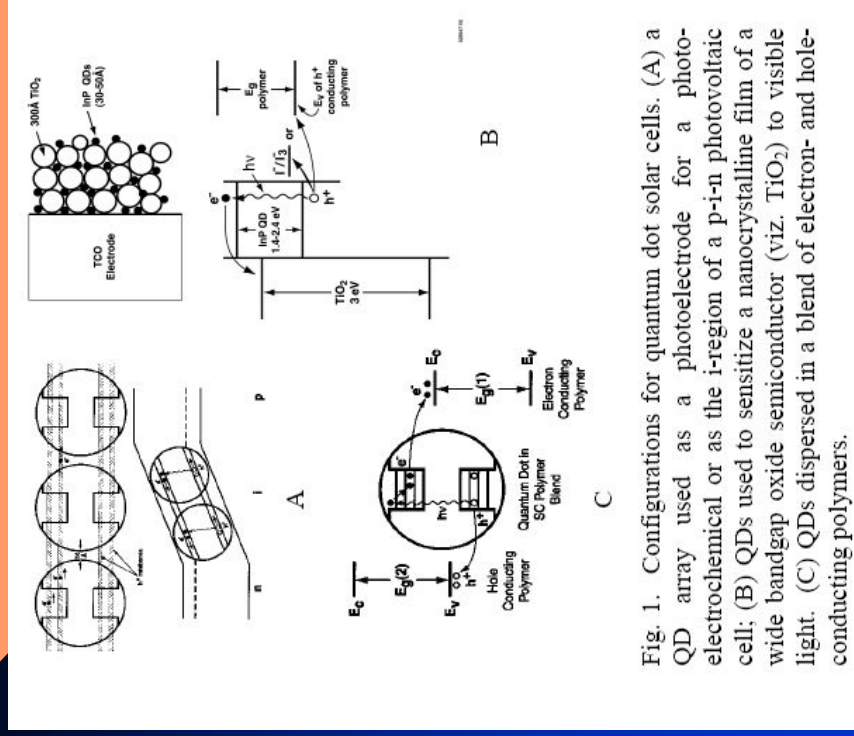


Fig. 1. Configurations for quantum dot solar cells. (A) a QD array used as a photoelectrode for a photochemical cell; (B) QDs used to sensitize a p-i-n photovoltaic cell; (C) QDs used to sensitize a nanocrystalline film of a wide bandgap oxide semiconductor (viz. TiO₂) to visible light. (C) QDs dispersed in a blend of electron- and hole-conducting polymers.

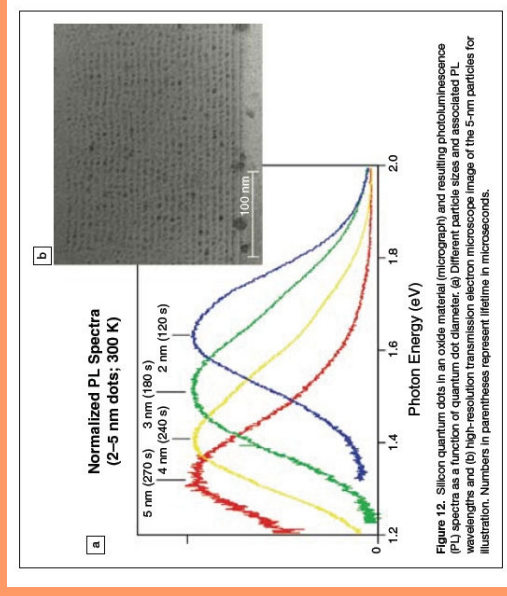


Figure 12. Silicon quantum dots in an oxide material (micrograph) and resulting photoluminescence (PL) spectra as a function of quantum dot diameter. (a) Different particle sizes and associated PL wavelengths and (b) high-resolution transmission electron microscope image of the 5-nm particles for illustration. Numbers in parentheses represent lifetime in microseconds.

Multi-exciton generation (MEG)

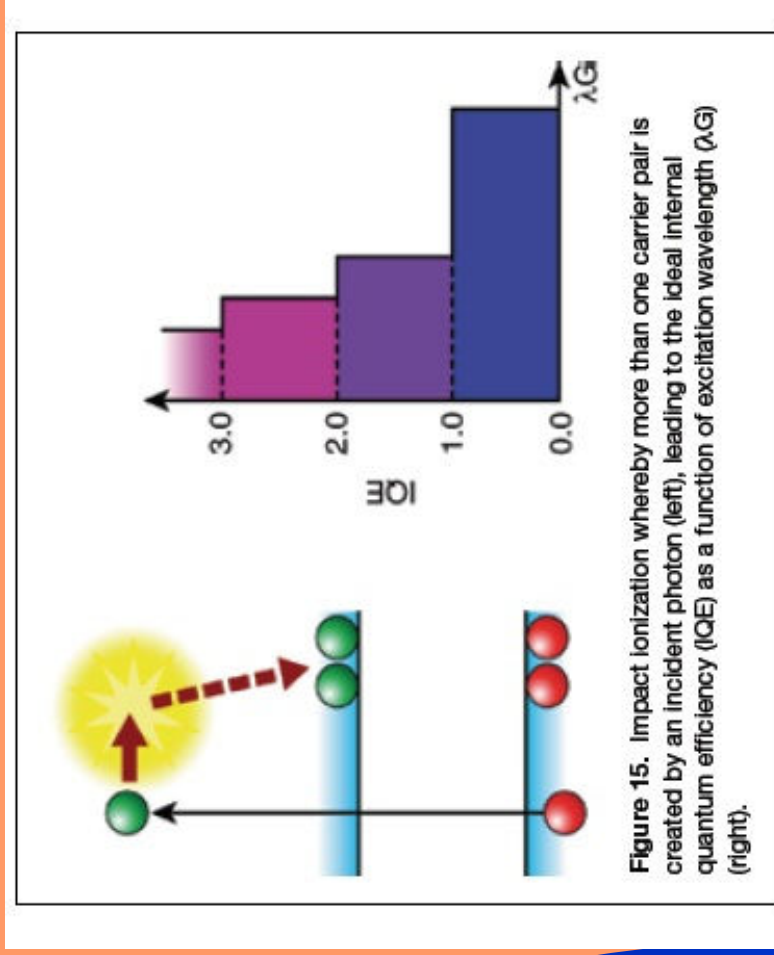
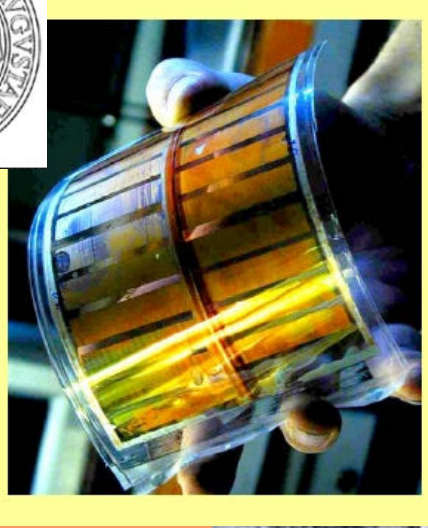
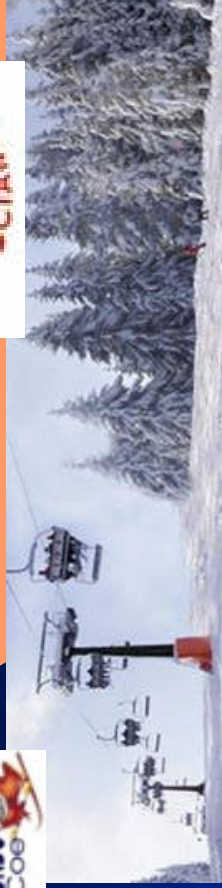
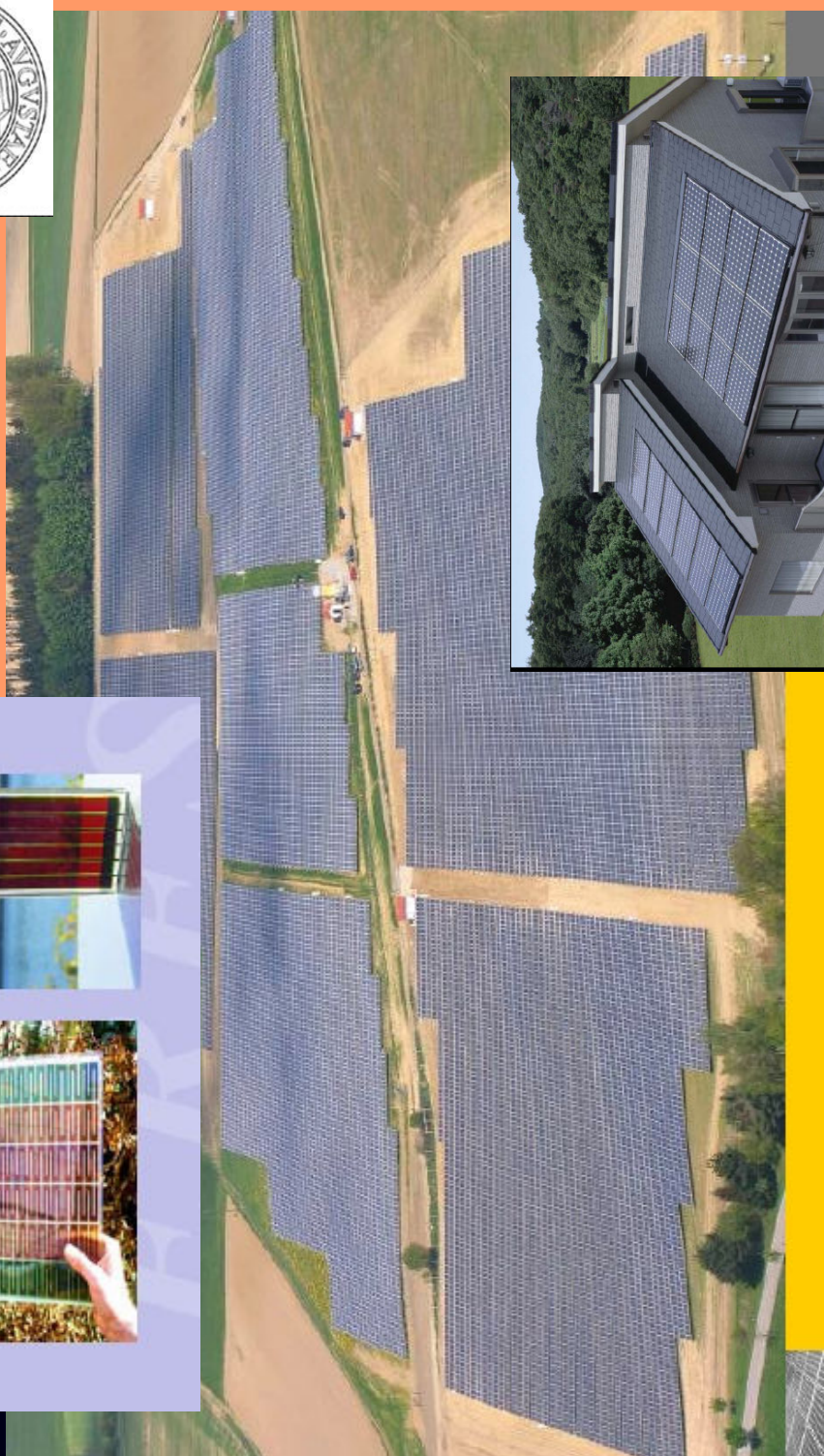


Figure 15. Impact ionization whereby more than one carrier pair is created by an incident photon (left), leading to the ideal internal quantum efficiency (IQE) as a function of excitation wavelength (λG) (right).



First European School on Thin Film Photovoltaics

Folgaria (Tn)
12 -17 January 2009





2007 market

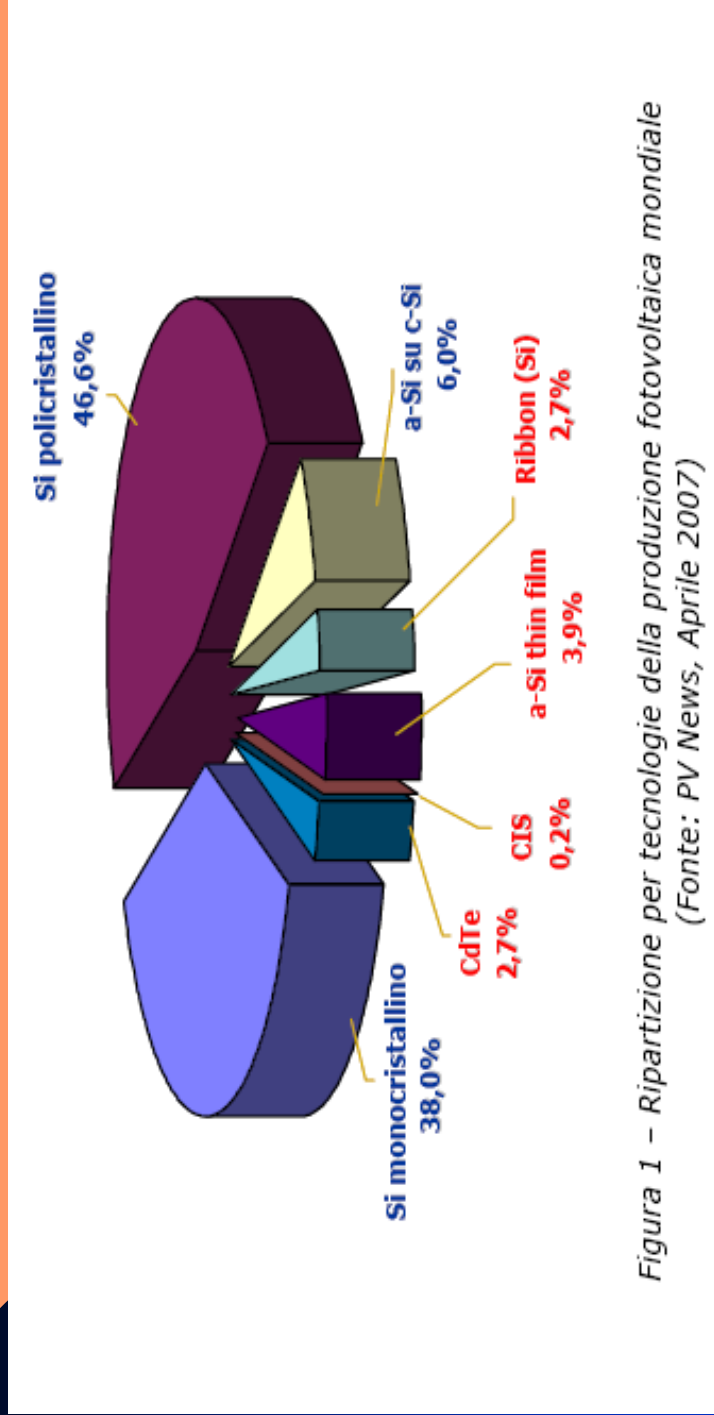
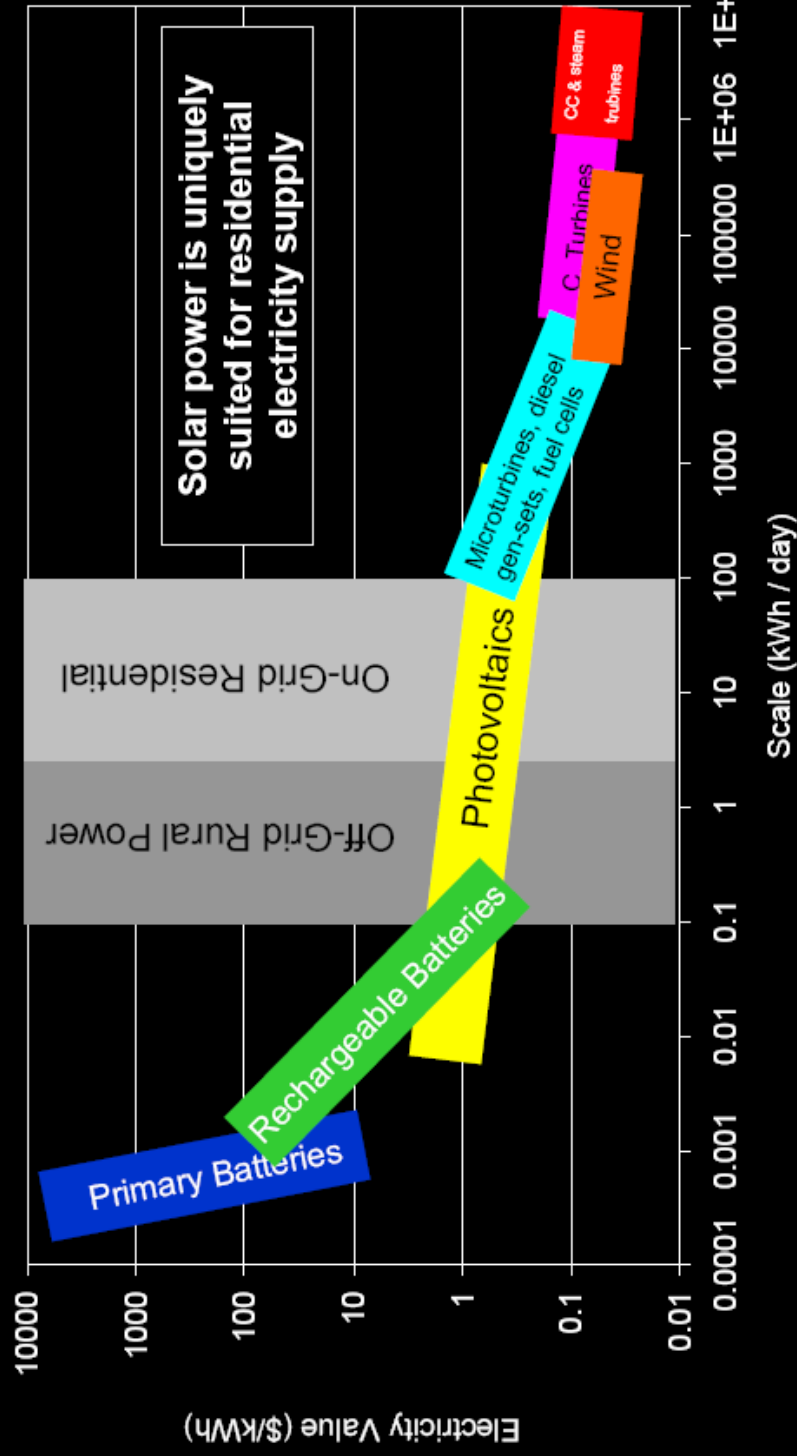


Figura 1 – Ripartizione per tecnologie della produzione fotovoltaica mondiale
(Fonte: PV News, Aprile 2007)

Fonte : ENEA

SUNPOWER Competing Technologies



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Multi-junction solar cells

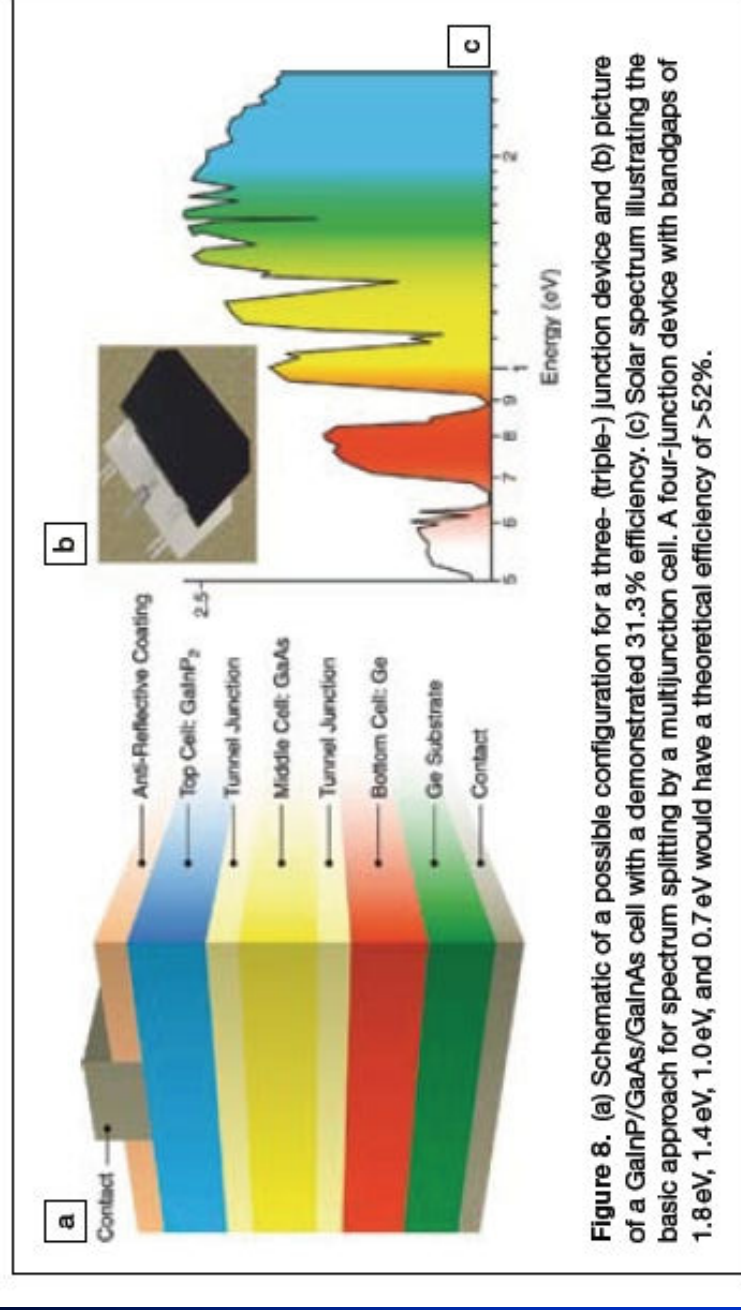


Figure 8. (a) Schematic of a possible configuration for a three- (triple-) junction device and (b) picture of a GaInP/GaAs/GaInAs cell with a demonstrated 31.3% efficiency. (c) Solar spectrum illustrating the basic approach for spectrum splitting by a multijunction cell. A four-junction device with bandgaps of 1.8 eV, 1.4 eV, 1.0 eV, and 0.7 eV would have a theoretical efficiency of >52%.

Thermodynamic limits

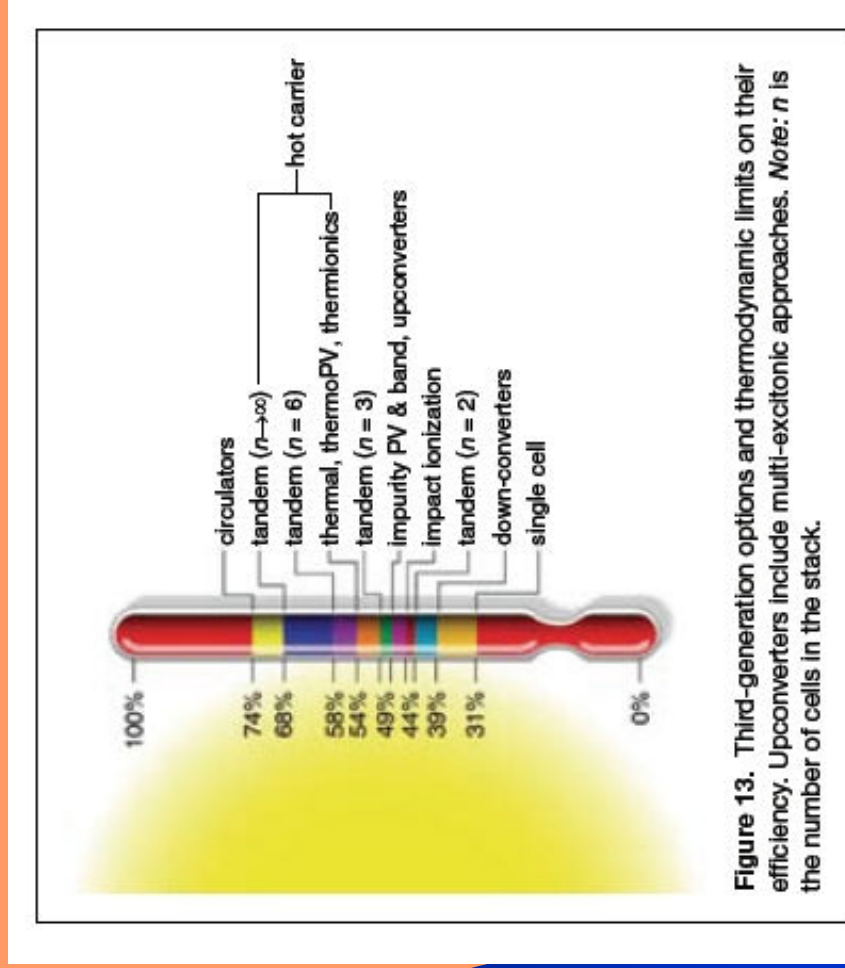


Figure 13. Third-generation options and thermodynamic limits on their efficiency. Upconverters include multi-excitonic approaches. Note: n is the number of cells in the stack.

Hot carriers approach

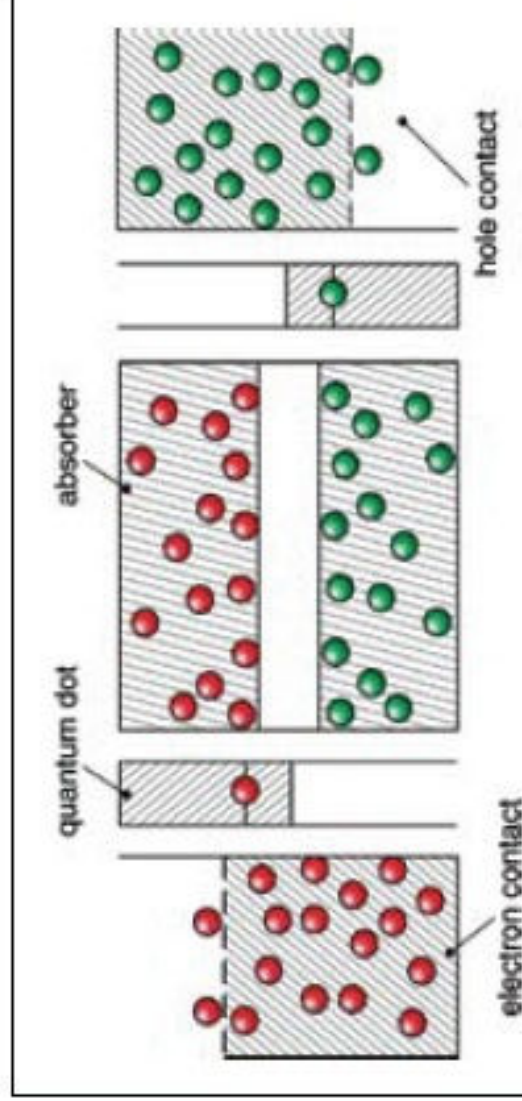


Figure 14. Hot-carrier cell schematic. Special properties are required for both the absorption volume and the carrier collection contacts.

CdTe and CIGS solar cells

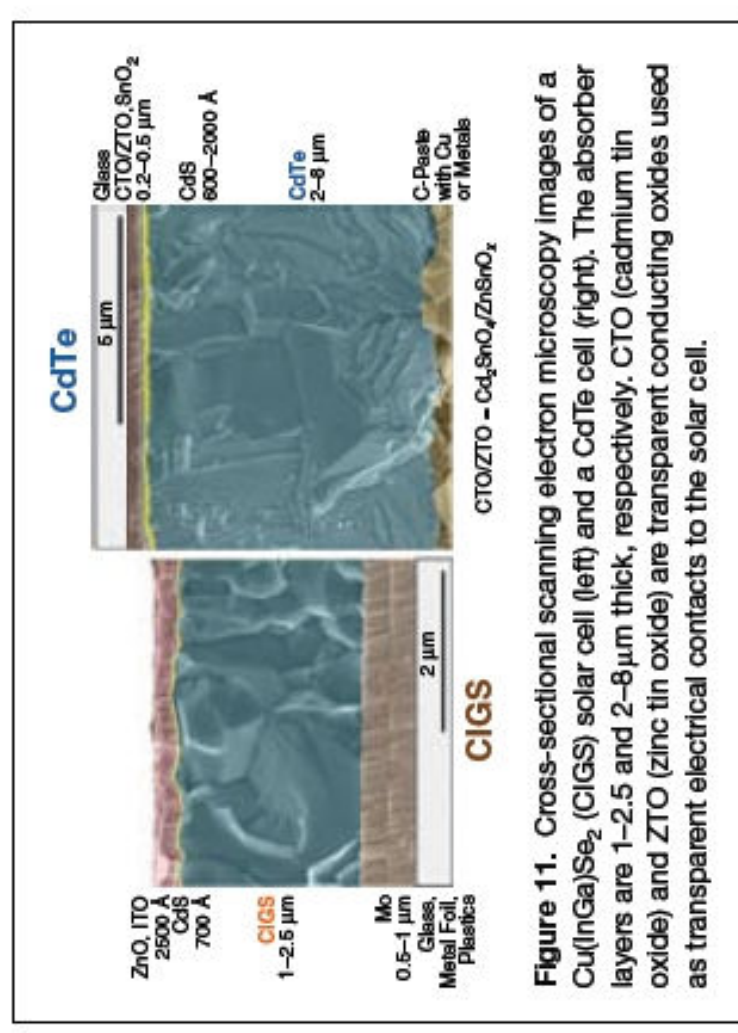


Figure 11. Cross-sectional scanning electron microscopy images of a Cu(InGa)Se₂ (CIGS) solar cell (left) and a CdTe cell (right). The absorber layers are 1–2.5 and 2–8 μm thick, respectively. CTO (cadmium tin oxide) and ZTO (zinc tin oxide) are transparent conducting oxides used as transparent electrical contacts to the solar cell.

Projected costs of PV modules

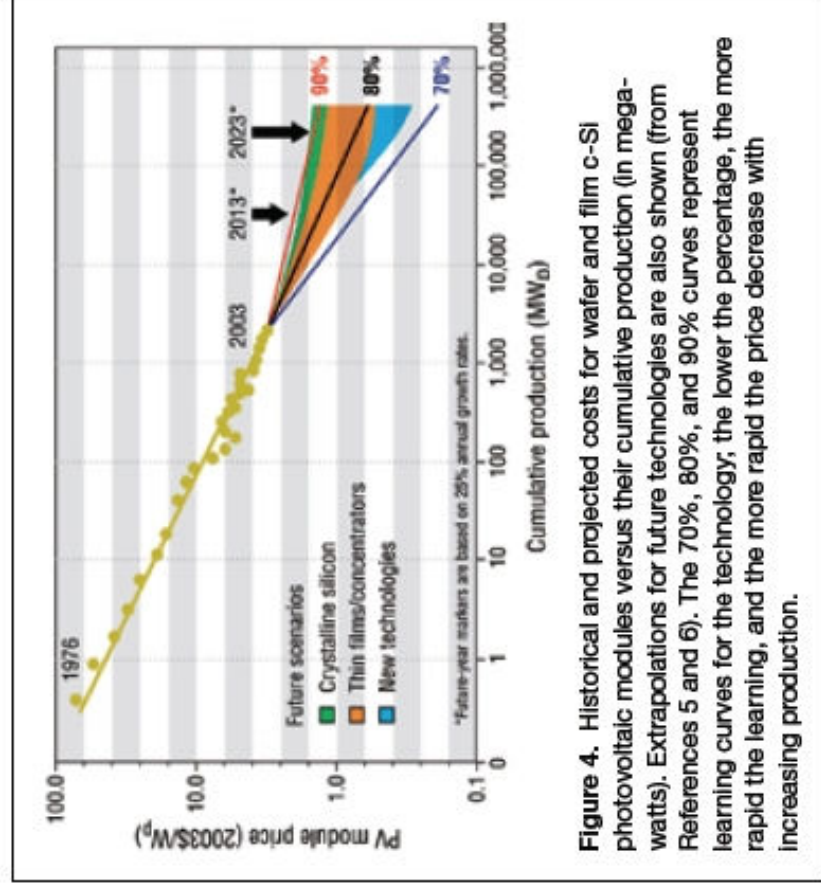


Figure 4. Historical and projected costs for wafer and film c-Si photovoltaic modules versus their cumulative production (in megawatts). Extrapolations for future technologies are also shown (from References 5 and 6). The 70%, 80%, and 90% curves represent learning curves for the technology; the lower the percentage, the more rapid the learning, and the more rapid the price decrease with increasing production.

Flexible solar cells

